

COM-TC

A0.2

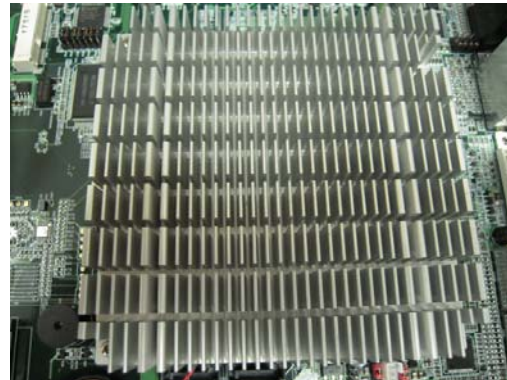
Thermal Image Analysis Report

Summary	<input checked="" type="checkbox"/> Pass <input type="checkbox"/> Fail <input type="checkbox"/> Pass with Deviation Comment: _____			
Test Result Summary				
	Critical	Major	Minor	Enhancement
Defect Found	0	0	0	0
Defect Unsolved	0	0	0	0

Issue date	Approval	Test Engineer
2011 / 11 / 22	Jansin Lee	Clement Chien

Sample Configuration & Quantity Under Test

- **Model name** : COM-TC
- **CPU Board** : COM-TC
- **Carrier Board** : ECB-916M B0.2
- **VGA Board** : ADD2-VGA R10
- **CPU** : Intel Atom Processor E620T / 1.30 GHz
- **Memory** : DDRII-SDRAM.800MHz SAMSUNG.K4T1G084QF-BCF7
- **HDD** : Seagate 3.5" SATA HDD 160GB
- **BIOS** : COM-TC T0.8
- **Test Software** : Windows XP / Run PassMark Burn In Test 6.0 Pro
- **Power** : ATX Power
- **Heat Sink:**



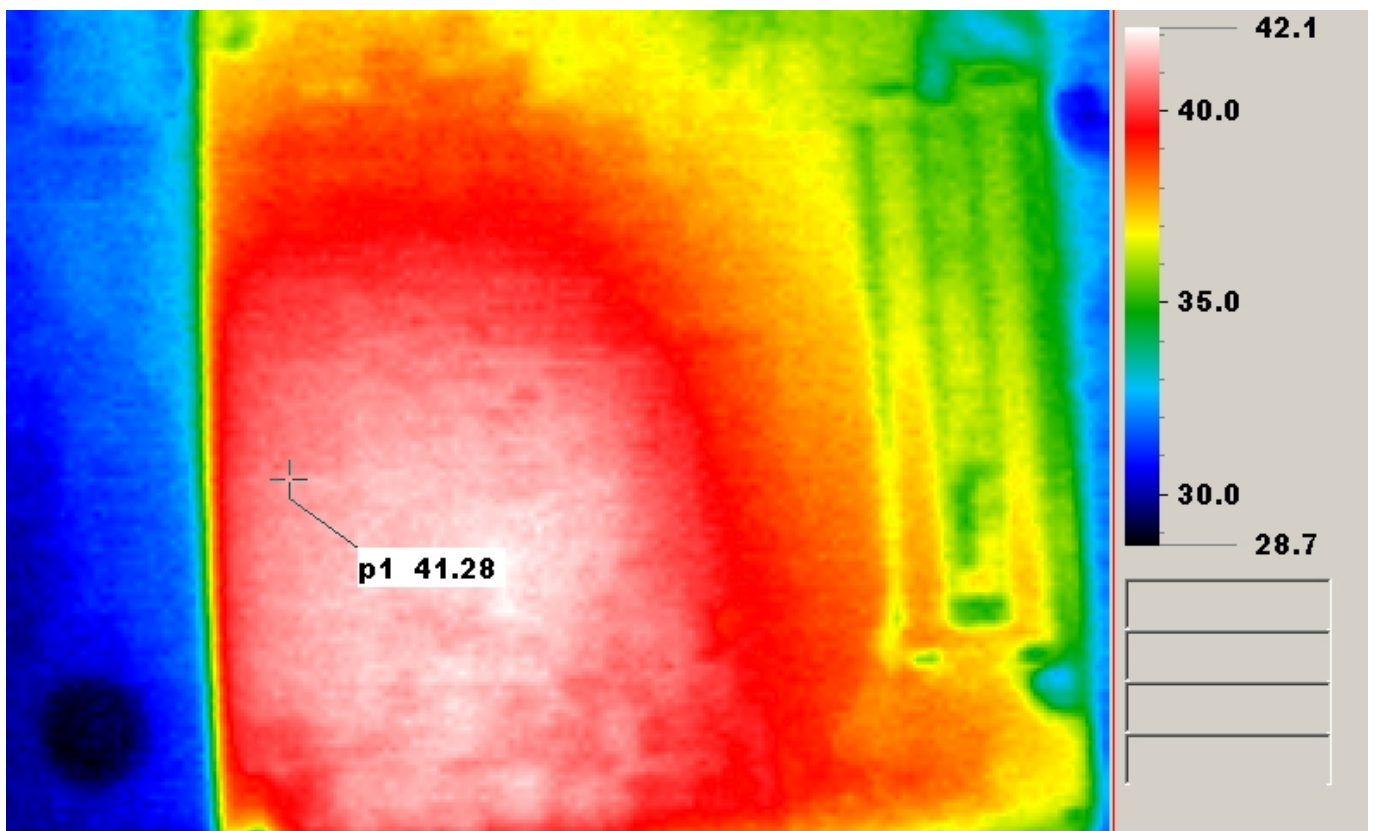
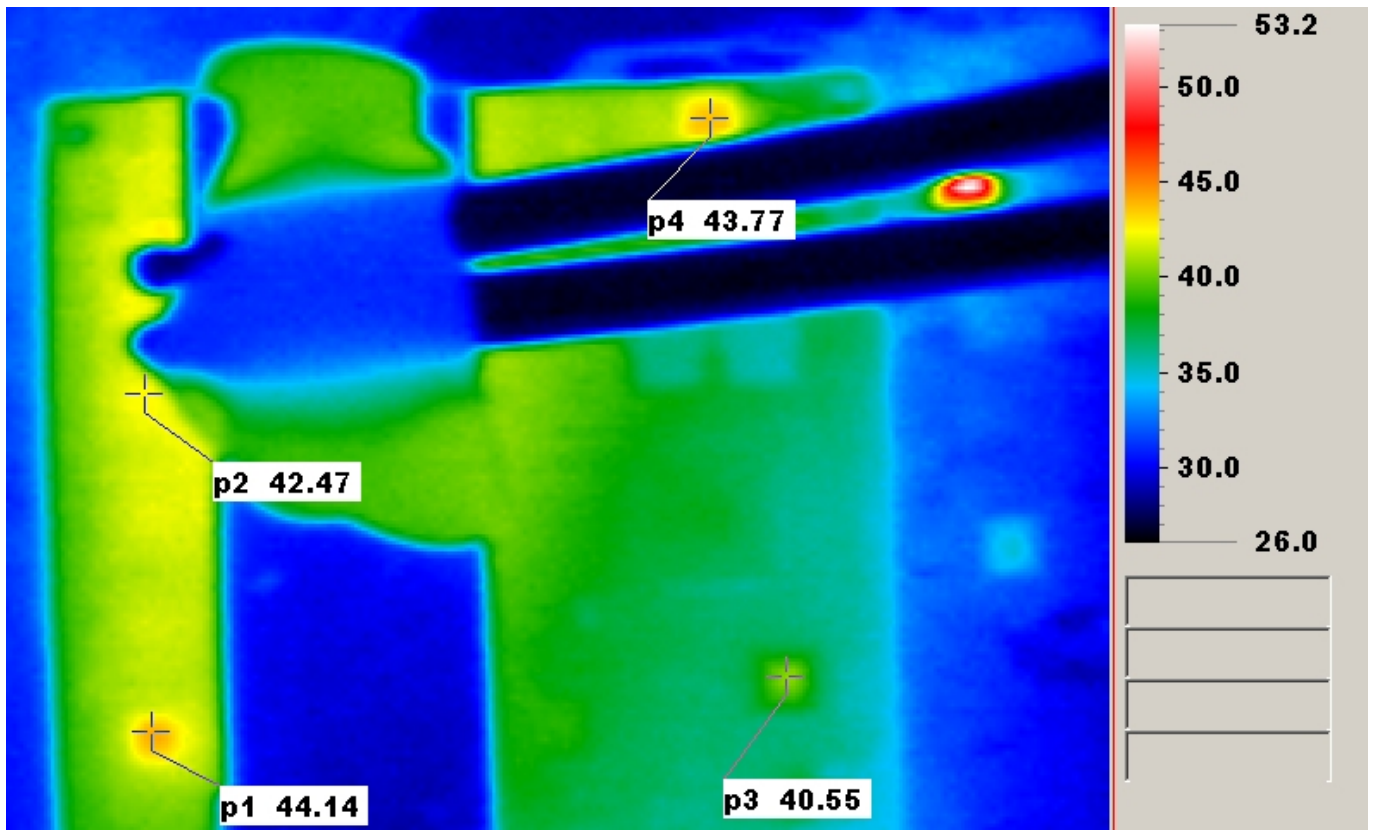
Thermal Image Analysis

1. Test Date: 2011-11-21
2. Test Product: COM-TC
3. Test Site: AAEON Internal Lab.
4. Temperature Measurement:
 - 4.1. 40 Channel Thermal Recorder:
 - 4.1.1 YOKOGAWA Inc,
 - 4.2.2 Model: DA100-13-1D
Date of Calibration: 2011/10/12
Serial Number: 12A323190
 - 4.2. IR Scanner: Infrared Camera
 - 4.2.1 NIPPON AVIONICS CO., LTD.
 - 4.2.2 Model: TVS-100
Date of Calibration: 2011/07/11
Serial Number: 0179L2746
5. Test Condition:

Component Side-1 (Test by DA-100): 25.0°C With Heat Sink
6. Take Picture Time:

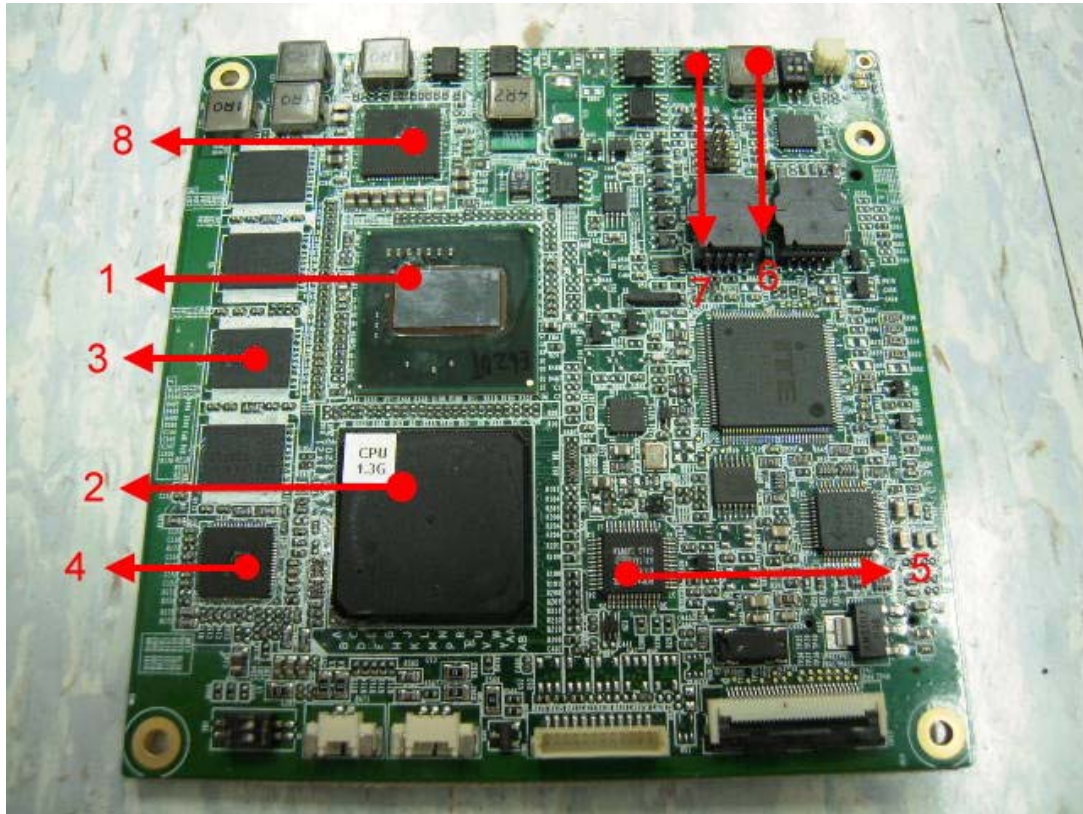
After power on 2 hours

Temperature Profile Test:
Component Side:



Terminal Recorder:

Measuring Thermal Couple Position :



Using YOKOGAWA / DARWIN DA100-100-13-1D test

Point	Position	Describe	Tc (*1) (°C)	Tm (*2) Measured Under		Note
				25°C	60°C	
1	U1	(TF)Intel CPU.Tunnel Creek Processor.1.3GHz(Premium)	110	44.8	79.8	
2	U13	(TF)Intel.EG20T.CS82TPCF.SLJ42	100	43.9	78.9	
3	U4	(TF)DDRII-SDRAM.800MHzSAMSUNG.K4T1G084QF-BCF7	95	43.9	78.9	
4	U12	(TF)UQFN64AV8080.CLK GEN.ROHM.BU7335MWV	100	46.3	81.3	
5	U22	(TF)PCI-Express.Gigabit Ethernet Chip.REALTEK.RTL8211CL-GR	100	44.2	79.2	
6	L14	(TF)COIL.[0.1~100]uH.20%.Zenithtek.ZPWM Series	125	43.7	78.7	
7	Q24	(TF)PWR.N-Channel.30V.10A.13.5mΩ.MOSFET.APEC.AP4410GM	125	43.9	78.9	
8	U27	(TF)UQFN088.ROHM.BD9591MWV	100	46.0	81.0	
9	U11	(TF)DDRII-SDRAM.800MHzSAMSUNG.K4T1G084QF-BCF7	95	43.9	78.9	

Note(*):

1. "Tc" indicates the component's case maximum temperature value specified in its datasheet.
2. "Tm" indicates the measured Tc value under working environmental temperature within product specification.

3. Judgment Criteria:

- **Fail** : $T_m > T_c + 5^{\circ}\text{C}$; The measured value is over specification plus margin.
- **Margin** : $T_c + 5^{\circ}\text{C} > T_m > T_c - 10^{\circ}\text{C}$; The measured value is within specification with margin.
 For FANLESS system application, it is strongly recommended to add thermal dissipation design for better reliability.
- **Pass** : $T_m < T_c - 10^{\circ}\text{C}$; The measured value is with safety margin.